



GaAs INTEGRATED CIRCUIT

μ PG2415T6X

0.05 to 6.0 GHz SPDT SWITCH

DESCRIPTION

The μ PG2415T6X is a GaAs MMIC SPDT (Single Pole Double Throw) switch for 0.05 to 6.0 GHz applications, including dual-band wireless LAN.

This device operates with dual control switching voltages of 2.7 to 3.3 V. This device can operate at frequencies from 0.05 to 6.0 GHz, with low insertion loss and high isolation.

This device is housed in a 6-pin plastic TSON (Thin Small Out-line Non-leaded) (T6X) package and is suitable for high-density surface mounting.

FEATURES

- Switch control voltage : $V_{\text{cont (H)}} = 3.0 \text{ V TYP.}$
: $V_{\text{cont (L)}} = 0 \text{ V TYP.}$
- Low insertion loss : $L_{\text{ins}} = 0.45 \text{ dB TYP. @ } f = 2.5 \text{ GHz}$
: $L_{\text{ins}} = 0.55 \text{ dB TYP. @ } f = 6.0 \text{ GHz}$
- High isolation : $ISL = 28 \text{ dB TYP. @ } f = 2.5 \text{ GHz}$
: $ISL = 26 \text{ dB TYP. @ } f = 6.0 \text{ GHz}$
- Handling power : $P_{\text{in (0.1 dB)}} = +31.0 \text{ dBm TYP. @ } f = 2.0 \text{ to } 6.0 \text{ GHz}$
- High-density surface mounting : 6-pin plastic TSON (T6X) package (1.5 × 1.5 × 0.37 mm)

APPLICATIONS

- Dual-band wireless LAN etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μ PG2415T6X-E2	μ PG2415T6X-E2-A	6-pin plastic TSON (T6X) (Pb-Free)	G6E	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 6 face the perforation side of the tape• Qty 3 kpcs/reel

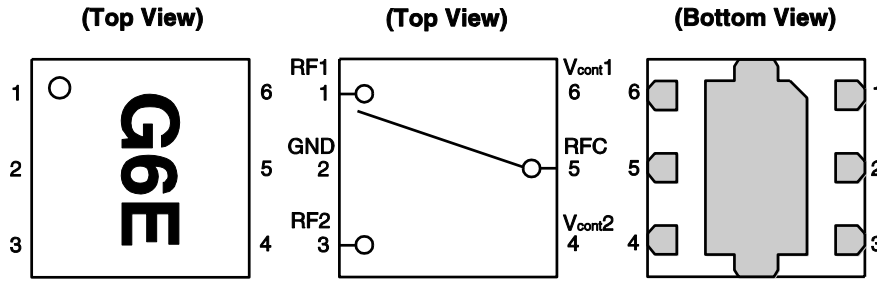
Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: μ PG2415T6X-A

Caution Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	RF1
2	GND
3	RF2
4	V _{cont2}
5	RFC
6	V _{cont1}

Remark Exposed pad :

GND

SW TRUTH TABLE

V _{cont1}	V _{cont2}	RFC-RF1	RFC-RF2
High	Low	ON	OFF
Low	High	OFF	ON

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	V _{cont}	+6.0 ^{Note}	V
Input Power	P _{in}	+36	dBm
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note |V_{cont1} - V_{cont2}| ≤ 6.0 V

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	0.05	-	6.0	GHz
Switch Control Voltage (H)	V _{cont (H)}	2.7	3.0	3.3	V
Switch Control Voltage (L)	V _{cont (L)}	-0.2	0	0.2	V
Control Voltage Difference	ΔV _{cont (H)} , ΔV _{cont (L)} ^{Note}	-0.1	0	0.1	V

Note ΔV_{cont (H)} = V_{cont1 (H)} - V_{cont2 (H)}
 ΔV_{cont (L)} = V_{cont1 (L)} - V_{cont2 (L)}

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{cont} (H) = 3.0 V, V_{cont} (L) = 0 V, Z_o = 50 Ω, DC blocking capacitors = 8 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	L _{ins1}	f = 0.05 to 0.5 GHz ^{Note 1}	–	0.35	–	dB
Insertion Loss 2	L _{ins2}	f = 0.5 to 2.0 GHz ^{Note 2}	–	0.40	0.65	dB
Insertion Loss 3	L _{ins3}	f = 2.0 to 2.5 GHz	–	0.45	0.70	dB
Insertion Loss 4	L _{ins4}	f = 2.5 to 3.8 GHz	–	0.55	0.80	dB
Insertion Loss 5	L _{ins5}	f = 3.8 to 6.0 GHz	–	0.55	0.80	dB
Isolation 1	ISL1	f = 0.05 to 0.5 GHz ^{Note 1}	–	30	–	dB
Isolation 2	ISL2	f = 0.5 to 2.0 GHz ^{Note 2}	25	28	–	dB
Isolation 3	ISL3	f = 2.0 to 2.5 GHz	25	28	–	dB
Isolation 4	ISL4	f = 2.5 to 3.8 GHz	25	28	–	dB
Isolation 5	ISL5	f = 3.8 to 6.0 GHz	22	26	–	dB
Return Loss 1	RL1	f = 0.05 to 0.5 GHz ^{Note 1}	–	20	–	dB
Return Loss 2	RL2	f = 0.5 to 2.0 GHz ^{Note 2}	15	20	–	dB
Return Loss 3	RL3	f = 2.0 to 2.5 GHz	15	20	–	dB
Return Loss 4	RL4	f = 2.5 to 6.0 GHz	10	15	–	dB
0.1 dB Loss Compression Input Power ^{Note 3}	P _{in} (0.1 dB)	f = 0.5 to 2.0 GHz ^{Note 2}	–	+32.0	–	dBm
		f = 2.0 to 6.0 GHz	–	+31.0	–	dBm
1 dB Loss Compression Input Power ^{Note 4}	P _{in} (1 dB)	f = 0.5 to 2.0 GHz ^{Note 2}	–	+36.0	–	dBm
		f = 2.0 to 6.0 GHz	–	+35.0	–	dBm
2nd Harmonics	2f ₀	f = 2.5 GHz, P _{in} = +20 dBm	–	80	–	dBc
3rd Harmonics	3f ₀	f = 2.5 GHz, P _{in} = +20 dBm	–	80	–	dBc
Input 3rd Order Intercept Point	IIP ₃	f = 2.5 GHz, P _{in} = +20 dBm	–	+60	–	dBm
Switch Control Current	I _{cont}	No RF input	–	0.1	10	μA
Switch Control Speed	t _{sw}	50% CTL to 90/10% RF	–	50	250	ns

Notes 1. DC blocking capacitors = 1 000 pF at f = 0.05 to 0.5 GHz

2. DC blocking capacitors = 56 pF at f = 0.5 to 2.0 GHz

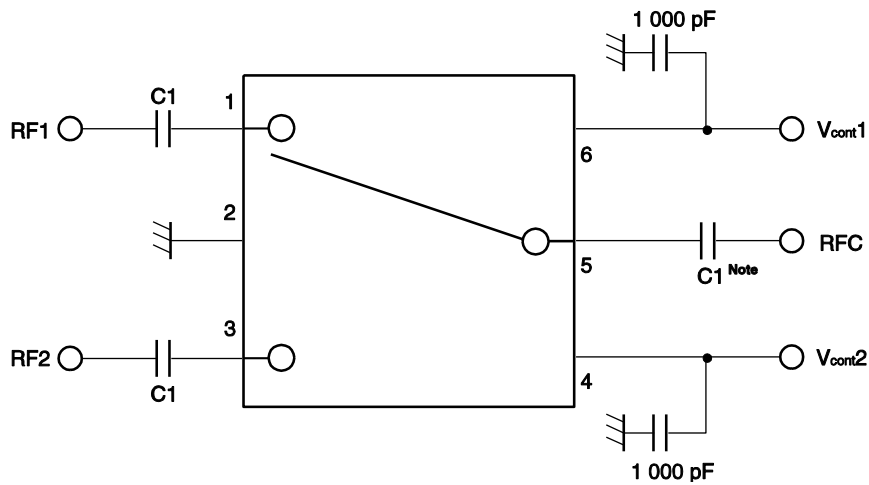
3. P_{in} (0.1 dB) is the measured input power level when the insertion loss increases 0.1 dB more than that of the linear range.

4. P_{in} (1 dB) is the measured input power level when the insertion loss increases 1 dB more than that of the linear range.

Caution It is necessary to use DC blocking capacitors with this device.

The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system.

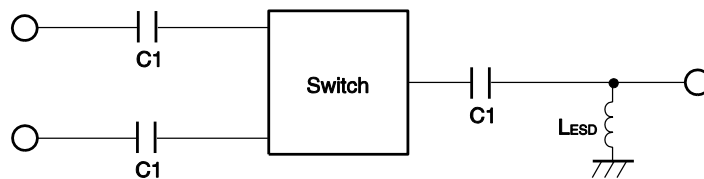
EVALUATION CIRCUIT



Note C1 : 0.05 to 0.5 GHz 1 000 pF
 : 0.5 to 2.0 GHz 56 pF
 : 2.0 to 6.0 GHz 8 pF

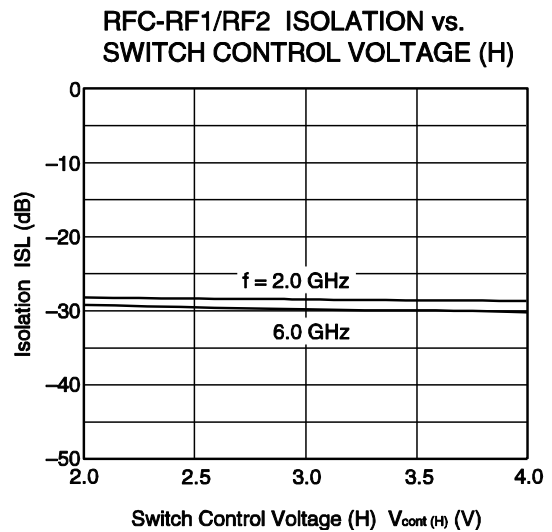
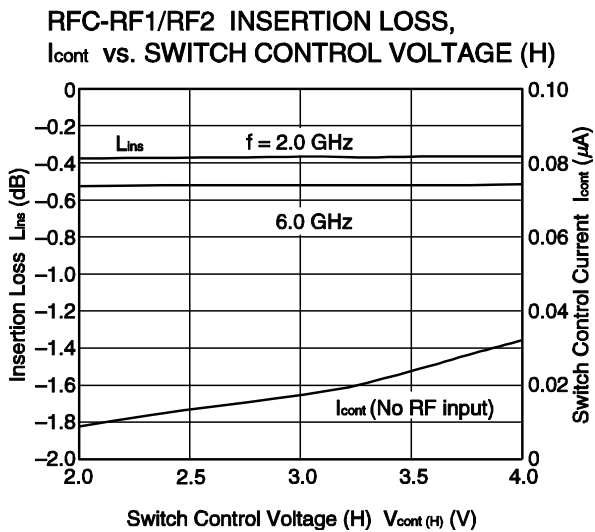
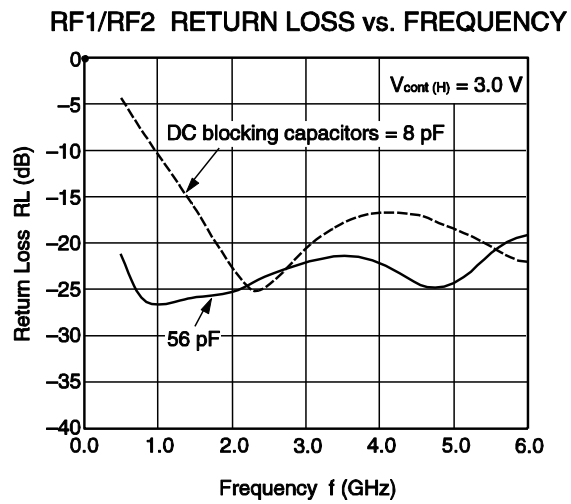
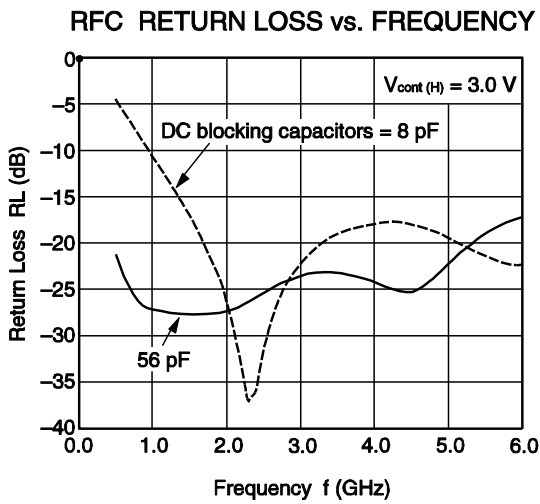
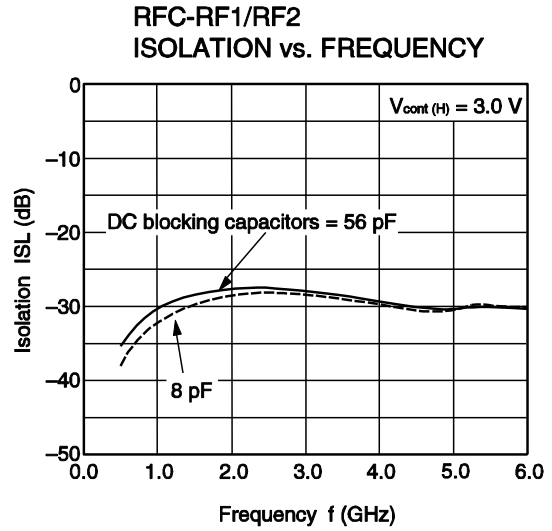
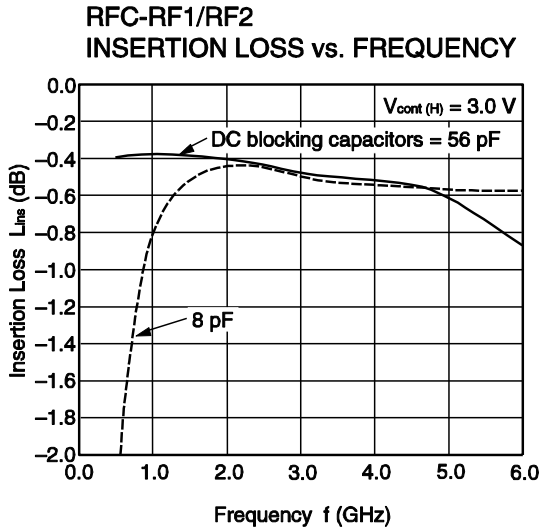
The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

APPLICATION INFORMATION



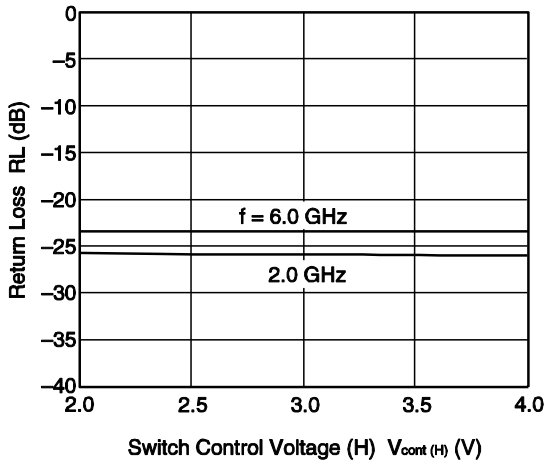
- C1 are DC blocking capacitors external to the device.
 The value may be tailored to provide specific electrical responses.
- The RF ground connections should be kept as short as possible and connected to directly to a good RF ground for best performance.
- L_{ESD} provides a means to increase the ESD protection on a specific RF port, typically the port attached to the antenna.

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{\text{cont (H)}} = 3.0\text{ V}$, $V_{\text{cont (L)}} = 0\text{ V}$, $Z_O = 50\ \Omega$, DC blocking capacitors = 8 pF, unless otherwise specified)

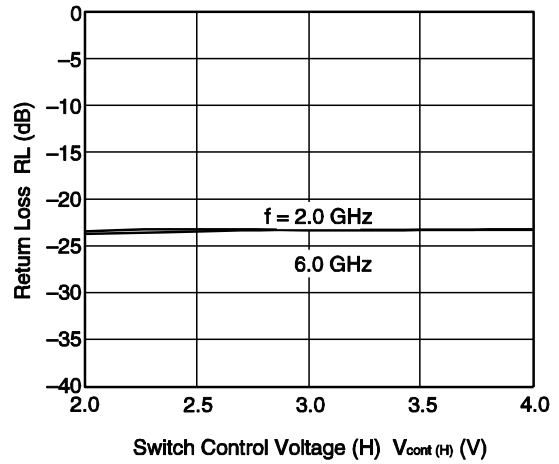


Remark The graphs indicate nominal characteristics.

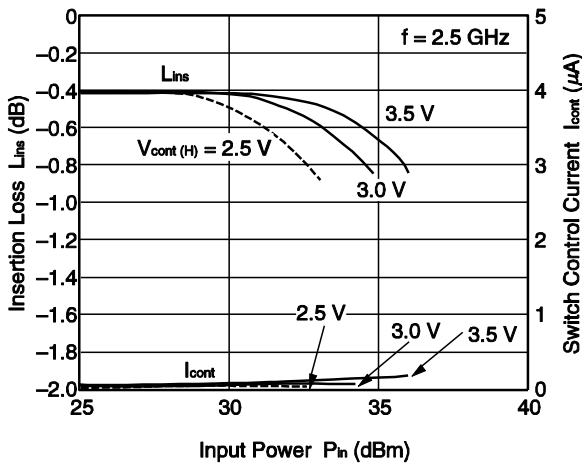
RFC RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



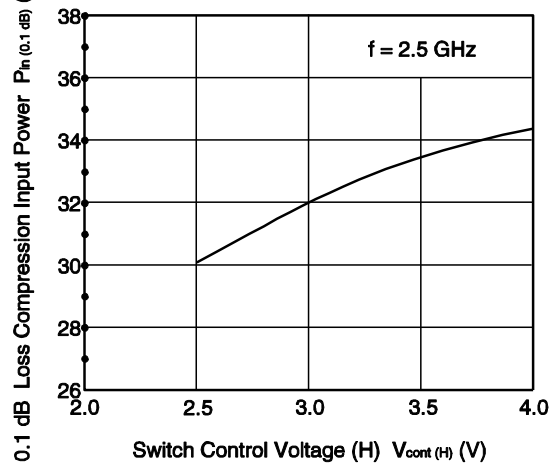
RF1/RF2 RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



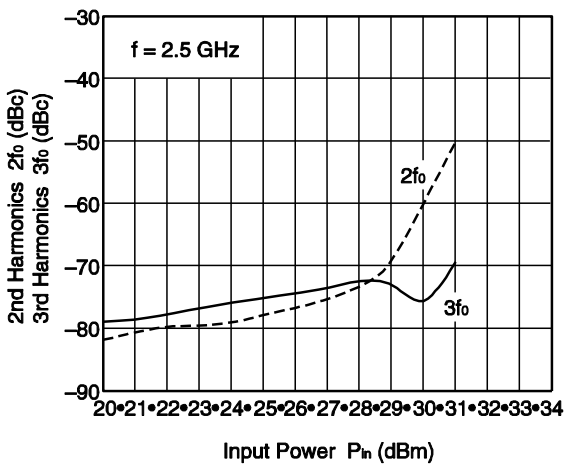
RFC-RF1/RF2 INSERTION LOSS, Icont vs. INPUT POWER



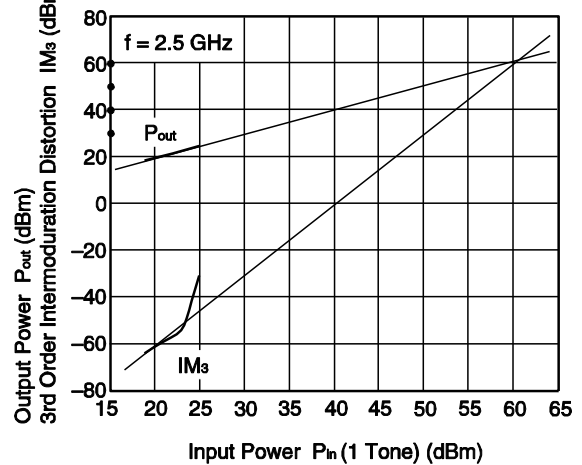
RFC-RF1/RF2 Pin (0.1 dB) vs. SWITCH CONTROL VOLTAGE (H)



RFC-RF1/RF2 • 2fo, 3fo vs. INPUT POWER



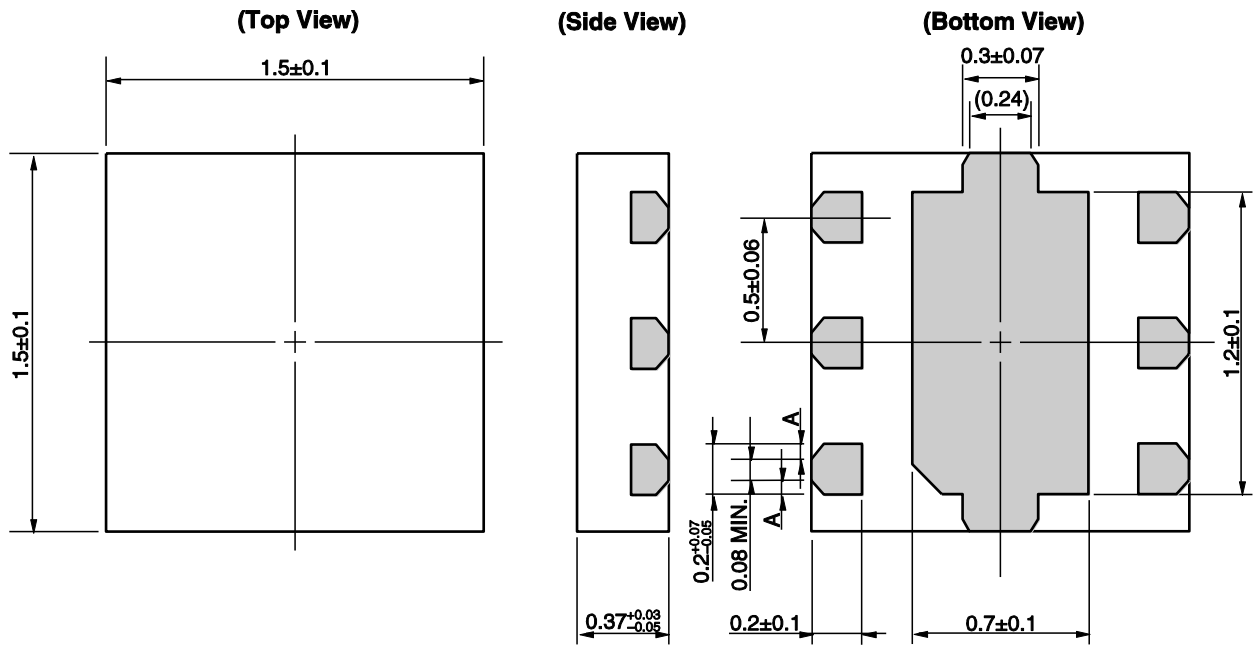
RFC-RF1/RF2 OUTPUT POWER, IM3 vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN PLASTIC TSON (T6X) (UNIT: mm)



Remark A>0

() : Reference value

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

<p>Caution GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. <ol style="list-style-type: none"> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. <ul style="list-style-type: none"> • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

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Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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